IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IAP20 Rec'd FCT/PTO 16 DEC 2005

In re Patent Application of

SUGIHARA ET AL. Atty. Ref.: 1035-616

Serial No. Unknown TC/A.U.: Unknown

Filed: December 16, 2005 Examiner: Unknown

For: SEMICONDUCTOR DEVICE, MANUFACTURING METHOD THEREOF,

AND ELECTRONIC DEVICE

December 16, 2005

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

INFORMATION DISCLOSURE STATEMENT

As suggested by 37 C.F.R. 1.97, the undersigned attorney brings to the attention of the Patent and Trademark Office the references listed on the attached form PTO/SB/08a. Copies of the listed foreign patent documents and articles are attached.

This is not to be construed as a representation that a search has been made or that no better prior art exists, or that a reference is relevant merely because cited.

The Examiner is requested to initial the attached form PTO/SB/08a and to return a copy of the initialed document to the undersigned as an indication that the attached references have been considered and made of record.

Respectfully submitted,

NIXON & VANDERHYE P.C.

By:

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Sheet 1 of 1

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1035-616 APPLICANT

SUGIHARA ET AL.

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Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to application.